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- 3-State Buffer-Type Noninverting Outputs Drive Bus Lines Directly
- Bus-Structured Pinout
- Buffered Control Inputs
- SN74ALS575A and 'AS575 Have Synchronous Clear
- Package Options Include Plastic Small-Outline (DW) Packages, Ceramic Chip Carriers (FK), Standard Plastic (N, NT) and Ceramic (J, JT) 300-mil DIPs, and Ceramic Flat (W) Packages

description

These octal D-type edge-triggered flip-flops feature 3-state outputs designed specifically for bus driving. They are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

The eight flip-flops enter data on the low-to-high transition of the clock (CLK) input. The SN74ALS575A, SN54AS575, and SN74AS575 may be synchronously cleared by taking the clear (CLR) input low.

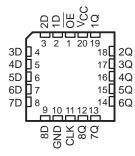
The output-enable (\overline{OE}) input does not affect internal operations of the flip-flops. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

The SN54ALS574B, SN54AS574, and SN54AS575 are characterized for operation over the full military temperature range of -55°C to 125°C. The SN74ALS574B, SN74ALS575A, SN74AS574, and SN74AS575 are characterized for operation from 0°C to 70°C.

SN54ALS574B, SN54AS574 . . . J OR W PACKAGE SN74ALS574B, SN74AS574 . . . DW OR N PACKAGE (TOP VIEW)

OE [1	O_{20}] ∨cc
1D [2	19	10
2D [3		2Q
3D [4	17	3Q
4D [5	16] 4Q
5D [6	15	5Q
6D [7	14] 6Q
7D [8	13] 7Q
8D [9	12] 8Q
GND [10	11	🛮 CLK

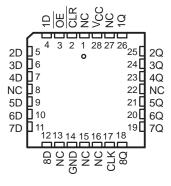
SN54ALS574B, SN54AS574 . . . FK PACKAGE (TOP VIEW)



SN54AS575 ... JT OR W PACKAGE SN74ALS575A, SN74AS575 ... DW OR NT PACKAGE (TOP VIEW)

CLR 1 24 V _C (OE 2 23 NC 1D 3 22 1Q
2D
GND 12 13 NC

SN54AS575 . . . FK PACKAGE (TOP VIEW)



NC - No internal connection



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Function Tables

SN54ALS574B, SN74ALS574B, SN54AS574, SN74AS574 (each flip-flop)

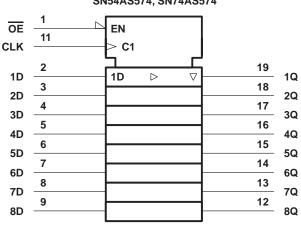
	INPUTS		OUTPUT
OE	CLK	D	Q
L	1	Н	Н
L	\uparrow	L	L
L	L	Χ	Q ₀
Н	X	Χ	Z

SN74ALS575A, SN54AS575, SN74AS575 (each flip-flop)

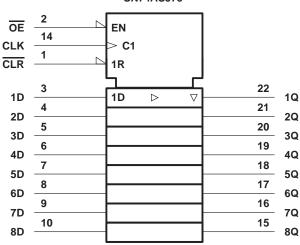
	INP	UTS		OUTPUT
OE	CLR	CLK	D	Q
L	L	1	Х	L
L	Н	\uparrow	Н	Н
L	Н	\uparrow	L	L
L	Н	L	Χ	Q_0
Н	X	Н	X	Z

logic symbols†

SN54ALS574B, SN74ALS574B, SN54AS574, SN74AS574



SN74ALS575A, SN54AS575, SN74AS575



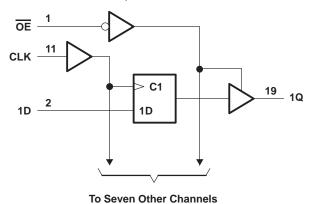
† These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the DW, J, JT, N, and NT packages.



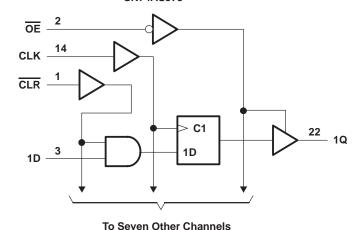
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logic diagrams (positive logic)

SN54ALS574B, SN74ALS574B, SN54AS574, SN74AS574



SN74ALS575A, SN54AS575, SN74AS575



10 Seven Ou

Pin numbers shown are for the DW, J, JT, N, and NT packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V _{CC}	7 V
Input voltage, V _I	7 V
Voltage applied to a disabled 3-state output	5.5 V
Operating free-air temperature range, T _A : SN54ALS574B	−55°C to 125°C
SN74ALS574B, SN74ALS575A	0°C to 70°C
Storage temperature range	-65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

				54ALS57	'4B		74ALS57 74ALS57		UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	
Vcc	Supply voltage		4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage		2			2			V
VIL	Low-level input voltage				0.7			0.8	V
ЮН	High-level output current				-1			-2.6	mA
loL	Low-level output current				12			24	mA
4	Clock fraguency	′ALS574B	0		28	0		35	MHz
fclock	Clock frequency	SN74ALS575A				0		30	IVITZ
	Pulse duration	'ALS574B, CLK high or low	16.5			14			
t _W	Pulse duration	SN74ALS575A, CLK high or low				16.5			ns
		Data	15			15			
t _{su}	Setup time before CLK↑	SN74ALS575A, CLR				15			ns
		Data	4			0			
^t h	Hold time after CLK↑	SN74ALS575A, CLR		•		0			ns
T _A	Operating free-air temperature	-	-55		125	0		70	°C



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

P/	ARAMETER	TEST CO	NDITIONS	SN5	4ALS57	'4B	SN74ALS574B SN74ALS575A			UNIT
				MIN	TYP [†]	MAX	MIN	TYP [†]	MAX	
VIK		$V_{CC} = 4.5 \text{ V},$	$I_{I} = -18 \text{ mA}$			-1.2			-1.2	V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V},$	$I_{OH} = -0.4 \text{ mA}$	V _{CC} -2	2		V _{CC} -2	!		
Vон		\\\a_= 4 \bullet \\	$I_{OH} = -1 \text{ mA}$	2.4	3.3					V
		V _{CC} = 4.5 V	$I_{OH} = -2.6 \text{ mA}$				2.4	3.2		
\/o:		V _{CC} = 4.5 V	I _{OL} = 12 mA		0.25	0.4		0.25	0.4	V
VOL		VCC = 4.5 V	I _{OL} = 24 mA					0.35	0.5	v
lozh		V _{CC} = 5.5 V,	V _O = 2.7 V			20			20	μΑ
lozL		$V_{CC} = 5.5 \text{ V},$	$V_0 = 0.4 \text{ V}$			-20			-20	μΑ
Ιį		V _{CC} = 5.5 V,	V _I = 7 V			0.1			0.1	mA
lіН		V _{CC} = 5.5 V,	V _I = 2.7 V			20			20	μΑ
I _I L		V _{CC} = 5.5 V,	V _I = 0.4 V			-0.2			-0.2	mA
lo [‡]		V _{CC} = 5.5 V,	V _O = 2.25 V	-20		-112	-30		-112	mA
			Outputs high		11	18		11	18	
	'ALS574B	V _{CC} = 5.5 V	Outputs low		17	27		17	27	
Icc			Outputs disabled		17	28		17	28	mA
	SN74ALS575A		Outputs high		10	17		10	17	
		V _{CC} = 5.5 V	Outputs low		15	24		15	24	
			Outputs disabled		16	30		16	30	

switching characteristics (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)		(/ _{CC} = 4.5 C _L = 50 pF R1 = 500 £ R2 = 500 £ F _A = MIN t	, 2, 2,			UNIT		
			SN54AL	S574B	SN74AL	4ALS574B SN74ALS575A					
			MIN	MAX	MIN	MAX	MIN	MAX			
f _{max}			28		35		30		MHz		
t _{PLH}	CLK	0	4	22	3	14	4	14	ns		
^t PHL	CLK	Q	4 17	17	4	14	4	14	115		
^t PZH	ŌĒ	•	4	21	3	18	4	18	ns		
t _{PZL}	OE	Q	4	26	4	18	4	18	115		
^t PHZ	ŌĒ	Q	2	16	1	10	2	10	ns		
t _{PLZ}	OE	ď	2	25	2	12	3	13	115		

[§] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.



[†] All typical values are at V_{CC} = 5 V, T_A = 25°C. ‡ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, I_{OS}.

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V _{CC}	7 V
Input voltage, V _I	7 V
Voltage applied to a disabled 3-state output	5.5 V
Operating free-air temperature range, T _A : SN54AS574, SN54AS575	−55°C to 125°C
SN74AS574, SN74AS575	0°C to 70°C
Storage temperature range	_65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

				N54AS57 N54AS57		SN74AS574 SN74AS575			UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	
VCC	Supply voltage		4.5	5	5.5	4.5	5	5.5	V
V_{IH}	High-level input voltage		2			2			V
VIL	Low-level input voltage				0.8			0.8	V
loh	High-level output current				-12			-15	mA
IOL	Low-level output current				32			48	mA
f _{clock} *	Clock frequency		0		100	0		90	MHz
+ *	Pulse duration	CLK high	5			5.5			ns
t _W *	ruise duration	CLK low	4			5.5			115
+ *	Out on the state OLIC	Data	3			5.5			ns
t _{su} *	Setup time before CLK↑	'AS575, CLR high or low	6.5			6.5			115
+. *	11-14 ti (t OLK)	Data	3			3			20
th*	Hold time after CLK↑	'AS575, CLR	0			0			ns
T _A	Operating free-air temperature		-55		125	0		70	°C

^{*} On products compliant to MIL-STD-883, Class B, this parameter is based on characterization data but is not production tested.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CO	NDITIONS		I54AS57 I54AS57			N74AS57 N74AS57		UNIT
				MIN	TYP [†]	MAX	MIN	TYP [†]	MAX	
٧ıK		V _{CC} = 4.5 V,	I _I = -18 mA			-1.2			-1.2	V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V},$	I _{OH} = −2 mA	V _{CC} -2)		V _{CC} -2	2		
Vон		V45V	$I_{OH} = -12 \text{ mA}$	2.4	3.2					V
		V _{CC} = 4.5 V	I _{OH} = -15 mA				2.4	3.3		
V = .		V 45V	I _{OL} = 32 mA		0.29	0.5				V
VOL		V _{CC} = 4.5 V	I _{OL} = 48 mA					0.34	0.5	V
lozh		V _{CC} = 5.5 V,	V _O = 2.7 V			50			50	μΑ
l _{OZL}		V _{CC} = 5.5 V,	V _O = 0.4 V			-50			-50	μΑ
Ц		V _{CC} = 5.5 V,	V _I = 7 V			0.1			0.1	mA
lн		V _{CC} = 5.5 V,	V _I = 2.7 V			20			20	μΑ
	OE, CLK, CLR	V 55V	V 0.4V			-0.5			-0.5	Λ
IIΓ	D	$V_{CC} = 5.5 \text{ V},$	V _I = 0.4 V			-3			-2	mA
IO [‡]	•	V _{CC} = 5.5 V,	V _O = 2.25 V	-30		-112	-30		-112	mA
			Outputs high		73	116		73	116	
	'AS574	V _{CC} = 5.5 V	Outputs low		85	134		85	134	
l.			Outputs disabled		84	134		84	134	mA
ICC			Outputs high		78	126		78	126	
	'AS575	V _{CC} = 5.5 V	Outputs low		89	142		89	142	
			Outputs disabled		88	142		88	142	

 $[\]uparrow$ All typical values are at V_{CC} = 5 V, T_A = 25°C.

switching characteristics (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	C _I R′ R2	CC = 4.5 = 50 pF I = 500 Ω 2 = 500 Ω A = MIN t	2, 2, o MAX§		UNIT
			SN54AS574 SN54AS575		SN74AS574 SN74AS575		
			MIN	MAX	MIN	MAX	
f _{max} *			100		90		MHz
^t PLH	CLK	Anu ()	3	11	3	8	ns
^t PHL	OLK	Any Q	4	11	4	9	113
^t PZH	ŌĒ	A O	2	7	2	6	ns
t _{PZL}	OE	Any Q	3	11	3	10	113
[†] PHZ	ŌĒ	Any Q	2	7	2	6	ns
^t PLZ	OE .	Ally Q	2	7	2	6	115

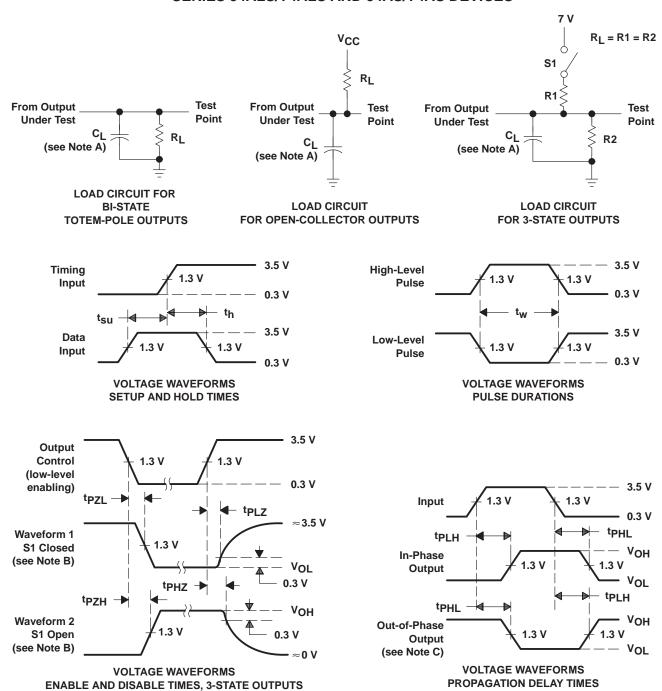
^{*} On products compliant to MIL-STD-883, Class B, this parameter is based on characterization data but is not production tested.



[‡] The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, los.

[§] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

PARAMETER MEASUREMENT INFORMATION SERIES 54ALS/74ALS AND 54AS/74AS DEVICES



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. When measuring propagation delay items of 3-state outputs, switch S1 is open.
- D. All input pulses have the following characteristics: PRR \leq 1 MHz, t_{Γ} = t_{f} = 2 ns, duty cycle = 50%.
- E. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuits and Voltage Waveforms



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